

2SC4928

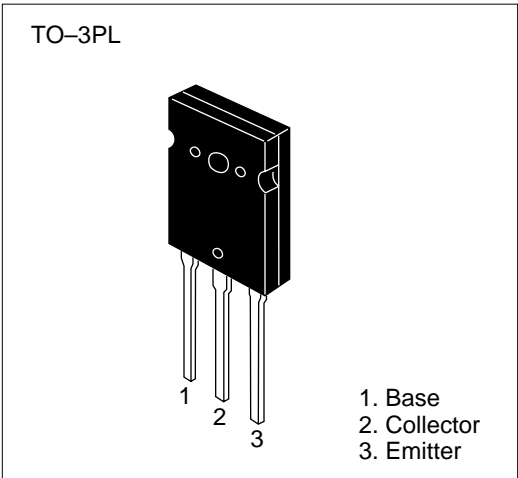
Silicon NPN Triple Diffused

Application

Character Display Horizontal Deflection Output

Features

- High speed switching time: 0.5  $\mu$ s max
- High breakdown voltage, high current:  
 $V_{CBO} = 1500\text{ V}$ ,  $I_C = 15\text{ A}$
- Suitable for large size CRT Display



Absolute Maximum Ratings (Ta = 25°C)

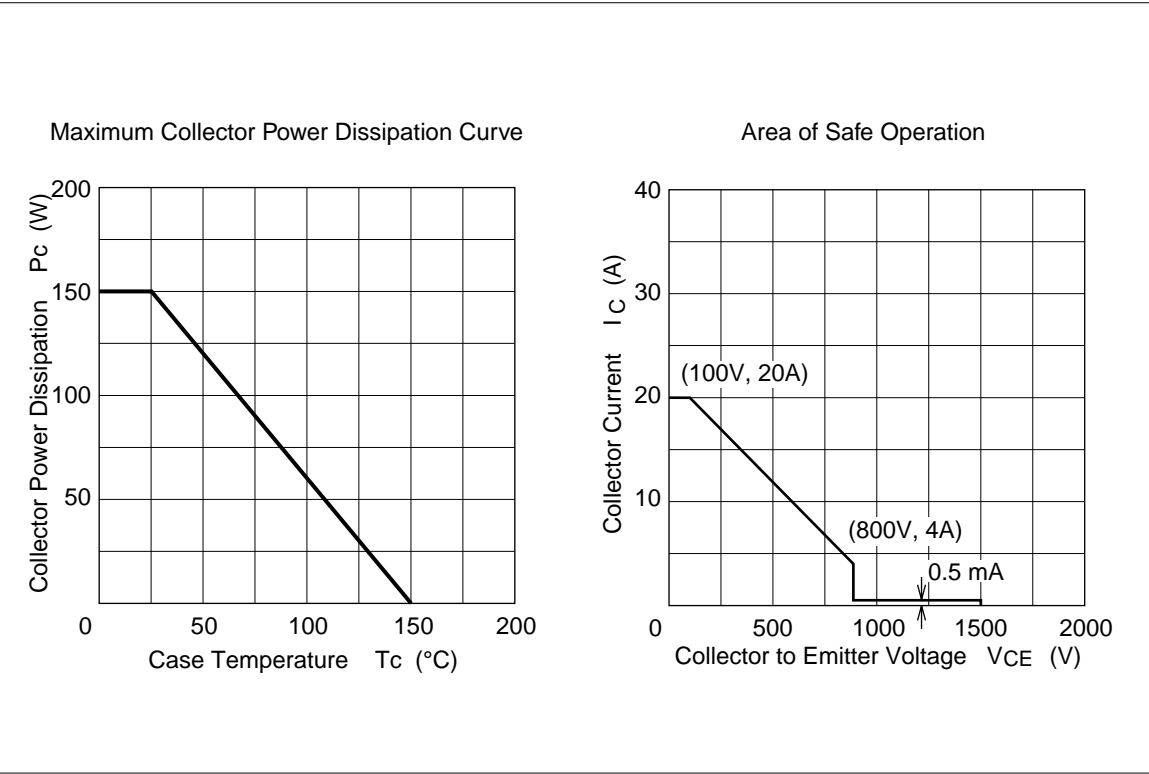
Item	Symbol	Rating	Unit
Collector to base voltage	$V_{CBO}$	1500	V
Collector to emitter voltage	$V_{CEO}$	800	V
Emitter to base voltage	$V_{EBO}$	6	V
Collector current	$I_C$	15	A
Collector surge current	$i_c(\text{surge})$	20	A
Collector power dissipation	$P_C^{*1}$	150	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Note: 1. Value at  $T_C = 25^\circ\text{C}$ .

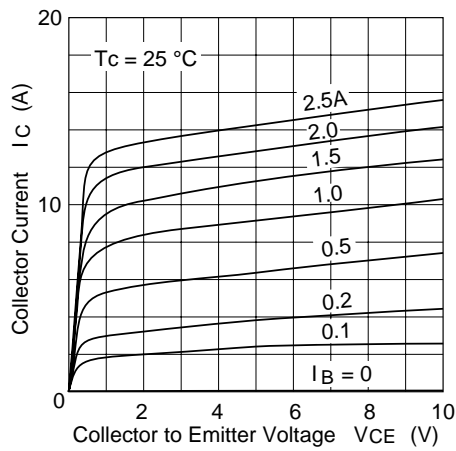
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Electrical Characteristics (Ta = 25°C)

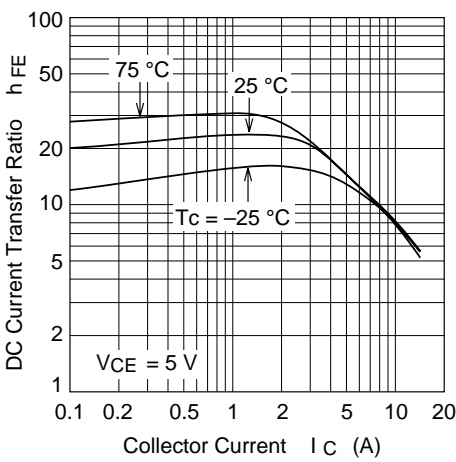
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	800	—	—	V	$I_C = 10\text{ mA}$ , $R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	6	—	—	V	$I_E = 10\text{ mA}$ , $I_C = 0$
Collector cutoff current	$I_{CES}$	—	—	500	$\mu\text{A}$	$V_{CE} = 1500\text{ V}$ , $R_{BE} = 0$
DC current transfer ratio	$h_{FE}$	—	—	38	—	$V_{CE} = 5\text{ V}$ , $I_C = 1\text{ A}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	5	V	$I_C = 12\text{ A}$ , $I_B = 3\text{ A}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	—	1.5	V	$I_C = 12\text{ A}$ , $I_B = 3\text{ A}$
Fall time	$t_f$	—	—	0.5	$\mu\text{s}$	$I_{CP} = 8\text{ A}$ , $I_{B1} = 1.4\text{ A}$ $I_{B2} \approx -2.5\text{ A}$ , $f_H = 31.5\text{ kHz}$



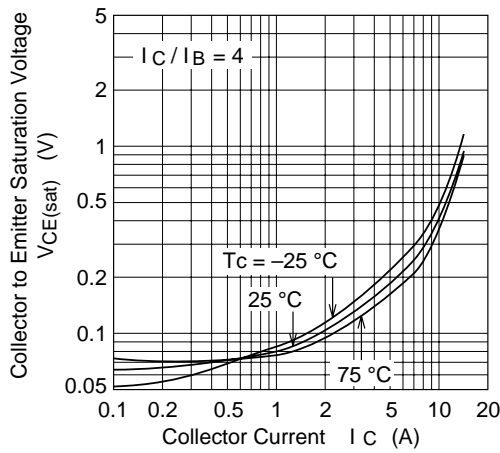
Typical Output Characteristics



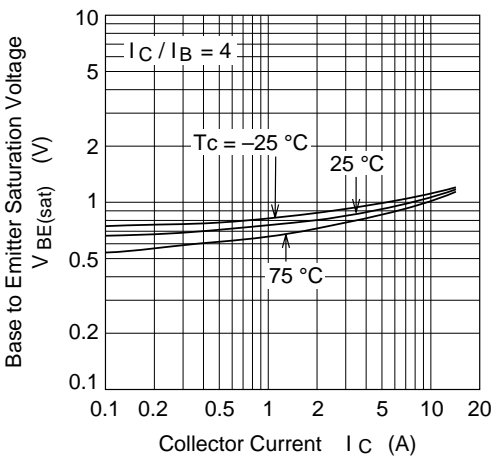
DC Current Transfer Ratio vs. Collector Current



Collector to Emitter Saturation Voltage vs. Collector Current



Base to Emitter Saturation Voltage vs. Collector Current



2SC4928

Collector to Emitter Saturation Voltage  
vs. Base Current

